## **APPLICATION DATA SHEET**

Electronic Version v14

Stylesheet Version v14.0

Title of Invention

[POLYSILICON THIN FILM TRANSISTOR AND METHOD OF FORMING

THE SAME]

Application Type: regular, utility 9893-US-PA Attorney Docket Number:

Correspondence address:

**Customer Number:** 31561

Priority Data:

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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.